

| Ref # | Hits   | Search Query   | DBs   | Default Operator | Plurals | Time Stamp       |
|-------|--------|--|-------|------------------|---------|------------------|
| L1    | 168384 | (TFT thin near2 film near2 transistor\$1 lcd soi silicon adj insulat\$4 display adj device electro\$1luminescence\$2 electro\$2ptical)   | USPAT | OR               | ON      | 2005/11/18 14:07 |
| L2    | 9      | ((double\$1layer\$3 two\$1layer\$3 multiple\$1layer\$4 multi\$1layer\$4)near3((gate)adj3(oxide nitride dielectric insulat\$4)))same (less adj thick\$4 more adj thick\$5 greater adj thick\$5 smaller adj thick\$5 thin\$4 near2 thick\$4 un\$1even near2 thick\$5 non\$1uniform near thick\$5)                            | USPAT | OR               | ON      | 2005/11/18 13:46 |
| L3    | 3      | 1 and 2  | USPAT | OR               | ON      | 2005/11/18 13:48 |
| L4    | 5987   | ((double\$1layer\$3 two\$1layer\$3 multiple\$1layer\$4 multi\$1layer\$4 first and second)near3((gate)adj3(oxide nitride dielectric insulat\$4)))   | USPAT | OR               | ON      | 2005/11/18 13:47 |
| L5    | 133913 | (less adj thick\$4 more adj thick\$5 greater adj thick\$5 smaller adj thick\$5 thin\$4 near2 thick\$4 un\$1even near2 thick\$5 non\$1uniform near thick\$5)  | USPAT | OR               | ON      | 2005/11/18 13:47 |
| L6    | 6804   | ((double\$1layer\$3 two\$1layer\$3 multiple\$1layer\$4 multi\$1layer\$4 first and second plurality)near3((gate)adj3(oxide nitride dielectric insulat\$4)))   | USPAT | OR               | ON      | 2005/11/18 13:47 |
| L7    | 250    | (less adj thick\$4 more adj thick\$5 greater adj thick\$5 smaller adj thick\$5 thin\$4 near2 thick\$4 un\$1even near2 thick\$5 non\$1uniform near thick\$5)same ((double\$1layer\$3 two\$1layer\$3 multiple\$1layer\$4 multi\$1layer\$4 first and second plurality)near3((gate)adj3(oxide nitride dielectric insulat\$4))) | USPAT | OR               | ON      | 2005/11/18 14:07 |
| L8    | 72     | 1 and 7  | USPAT | OR               | ON      | 2005/11/18 13:49 |

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| L9  | 133    | (less adj thick\$4 more adj thick\$5 greater adj thick\$5 smaller adj thick\$5 thin\$4 near2 thick\$4 un\$1even near2 thick\$5 non\$1uniform near thick\$5)near11 ((double\$1layer\$3 two\$1layer\$3 multiple\$1layer\$4 multi\$1layer\$4 first and second plurality)near3((gate)adj3(oxide nitride dielectric insulat\$4))) | USPAT    | OR | ON | 2005/11/18 14:07 |
| L10 | 34     | 1 and 9  | USPAT    | OR | ON | 2005/11/18 13:49 |
| L11 | 114309 | (TFT thin near2 film near2 transistor\$1 lcd soi silicon adj insulat\$4 display adj device electro\$1luminescence\$2 electro\$2ptical)   | US-PGPUB | OR | ON | 2005/11/18 14:30 |
| L12 | 110    | (less adj thick\$4 more adj thick\$5 greater adj thick\$5 smaller adj thick\$5 thin\$4 near2 thick\$4 un\$1even near2 thick\$5 non\$1uniform near thick\$5)near11 ((double\$1layer\$3 two\$1layer\$3 multiple\$1layer\$4 multi\$1layer\$4 first and second plurality)near3((gate)adj3(oxide nitride dielectric insulat\$4))) | US-PGPUB | OR | ON | 2005/11/18 14:44 |
| L13 | 31     | 11 and 12  | US-PGPUB | OR | ON | 2005/11/18 14:21 |
| L14 | 3910   | ((double\$1layer\$3 two\$1layer\$3 multiple\$1layer\$4 multi\$1layer\$4 first and second plurality)near3((gate)adj3(oxide nitride dielectric insulat\$4)))   | US-PGPUB | OR | ON | 2005/11/18 14:29 |
| L15 | 1793   | 11 and 14  | US-PGPUB | OR | ON | 2005/11/18 14:30 |
| L16 | 1377   | 257/72 257/59 349/42-43 349/45. ccls.  | US-PGPUB | OR | ON | 2005/11/18 14:37 |
| L17 | 267    | 15 and 16  | US-PGPUB | OR | ON | 2005/11/18 14:30 |
| L18 | 2388   | ((double\$1layer\$3 two\$1layer\$3 multiple\$1layer\$4 multi\$1layer\$4 first and second plurality)near3((gate)adj3(oxide nitride dielectric insulat\$4))).ab, clm.  | US-PGPUB | OR | ON | 2005/11/18 14:37 |
| L19 | 953    | 11 and 18  | US-PGPUB | OR | ON | 2005/11/18 14:31 |
| L20 | 153    | 19 and 16  | US-PGPUB | OR | ON | 2005/11/18 14:31 |
| L21 | 10438  | (TFT thin near2 film near2 transistor\$1 lcd soi silicon adj insulat\$4 display adj device electro\$1luminescence\$2 electro\$2ptical).ti.   | US-PGPUB | OR | ON | 2005/11/18 14:43 |
| L22 | 261    | 21 and 18  | US-PGPUB | OR | ON | 2005/11/18 14:31 |

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| L23 | 81     | 22 and 16   | US-PGPUB          | OR | ON | 2005/11/18 14:31 |
| L24 | 18225  | (TFT thin near2 film near2 transistor\$1 lcd soi silicon adj insulat\$4 display adj device electro\$1luminescence\$2 electro\$2ptical).ti.  | USPAT             | OR | ON | 2005/11/18 14:36 |
| L25 | 4108   | ((double\$1layer\$3 two\$1layer\$3 multiple\$1layer\$4 multi\$1layer\$4 first and second plurality)near3((gate)adj3(oxide nitride dielectric insulat\$4))).ab, clm.   | USPAT             | OR | ON | 2005/11/18 14:44 |
| L26 | 323    | 24 and 25   | USPAT             | OR | ON | 2005/11/18 14:37 |
| L27 | 2704   | 257/72 257/59 349/42-43 349/45. ccls.   | USPAT             | OR | ON | 2005/11/18 14:54 |
| L28 | 125    | 26 and 27   | USPAT             | OR | ON | 2005/11/18 14:38 |
| L29 | 404613 | (TFT thin near2 film near2 transistor\$1 lcd soi silicon adj insulat\$4 display adj device electro\$1luminescence\$2 electro\$2ptical)  | EPO; JPO; DERWENT | OR | ON | 2005/11/18 14:43 |
| L30 | 2721   | ((double\$1layer\$3 two\$1layer\$3 multiple\$1layer\$4 multi\$1layer\$4 first and second plurality)near3((gate)adj3(oxide nitride dielectric insulat\$4))).ab, clm.   | EPO; JPO; DERWENT | OR | ON | 2005/11/18 14:44 |
| L31 | 2822   | ((double\$1layer\$3 two\$1layer\$3 multiple\$1layer\$4 multi\$1layer\$4 first and second plurality)near3((gate)adj3(oxide nitride dielectric insulat\$4)))  | EPO; JPO; DERWENT | OR | ON | 2005/11/18 14:44 |
| L32 | 2721   | 30 and 31   | EPO; JPO; DERWENT | OR | ON | 2005/11/18 14:45 |
| L33 | 77     | (less adj thick\$4 more adj thick\$5 greater adj thick\$5 smaller adj thick\$5 thin\$4 near2 thick\$4 un\$1even near2 thick\$5 non\$1uniform near thick\$5)and ((double\$1layer\$3 two\$1layer\$3 multiple\$1layer\$4 multi\$1layer\$4 first and second plurality)near3((gate)adj3(oxide nitride dielectric insulat\$4))) | EPO; JPO; DERWENT | OR | ON | 2005/11/18 14:48 |
| L34 | 10     | 29 and 33   | EPO; JPO; DERWENT | OR | ON | 2005/11/18 14:48 |

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| L35 | 53602 | (less adj thick\$4 more adj thick\$5<br>greater adj thick\$5 smaller adj<br>thick\$5 thin\$4 near2 thick\$4<br>un\$1even near2 thick\$5<br>non\$1uniform near thick\$5) | EPO; JPO;<br>DERWENT | OR | ON | 2005/11/18 14:50 |
| L36 | 1550  | 29 and 35   | EPO; JPO;<br>DERWENT | OR | ON | 2005/11/18 14:51 |
| L37 | 1211  | 257/72 257/59 349/42-43 349/45.<br>ccls.  | EPO; JPO             | OR | ON | 2005/11/18 14:49 |
| L38 | 5     | 36 and 37   | EPO; JPO             | OR | ON | 2005/11/18 14:49 |
| L39 | 1368  | (irregular\$3 near thick\$5)  | EPO; JPO;<br>DERWENT | OR | ON | 2005/11/18 14:51 |
| L40 | 56    | 29 and 39   | EPO; JPO;<br>DERWENT | OR | ON | 2005/11/18 14:53 |
| L41 | 2     | (irregular\$3 near<br>thick\$5)near5((gate)adj3(oxide<br>nitride dielectric insulat\$4))  | EPO; JPO;<br>DERWENT | OR | ON | 2005/11/18 14:52 |
| L42 | 65    | (irregular\$3 un\$1even<br>non\$1uniform\$4)near5((gate)adj3<br>(oxide nitride dielectric insulat\$4))  | EPO; JPO;<br>DERWENT | OR | ON | 2005/11/18 14:54 |
| L43 | 8     | 29 and 42   | EPO; JPO;<br>DERWENT | OR | ON | 2005/11/18 14:53 |
| L44 | 375   | (irregular\$3 un\$1even<br>non\$1uniform\$4)near5((gate)adj3<br>(oxide nitride dielectric insulat\$4))  | US-PGPUB;<br>USPAT   | OR | ON | 2005/11/18 14:54 |
| L45 | 4081  | 257/72 257/59 349/42-43 349/45.<br>ccls.  | US-PGPUB;<br>USPAT   | OR | ON | 2005/11/18 14:54 |
| L46 | 17    | 44 and 45   | US-PGPUB;<br>USPAT   | OR | ON | 2005/11/18 14:55 |